A new half metallic quaternary Heusler alloys for spin polarized device application and waste heat recovery treatment: Material computation



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Abstract

- ✓ In this article, we have studied the structural, electronic, magnetic, mechanical and thermoelectric properties of new quaternary Heusler alloys FeZrTiZ (Z=Si, Sn, Pb), using ab-initio simulation methods.
- Our structural phase stability studies show that all these compounds stabilize in Y1-type structure and showing ferromagnetic ground state.
- From the calculation based on Generalized Gradient Approximation method, we found that all these alloys having half metallic behavior with the band gap in one of the spin channels.

Methodology

- **In our work the calculations have been done using density functional theory** (DFT) method which is implemented in WIEN2k package.
- The WIEN2k package is a computer program written in Fortran which performs quantum mechanical calculations on periodic solids. It uses the fullpotential linearized augmented plane-wave [FPLA-PW] basis set to solve the Kohn–Sham equations of density functional theory..
- **WIEN2k** was originally developed by Peter Blaha and Karlheinz Schwarz from the Institute of Materials Chemistry of the Vienna University of

Results

Alloy	Туре	E ₀ (Ry)		a _o (Å)	V(a.u.)3	Structural stability	
		FM	NM				
FeZrTiSi	Y1	-12031.8135	-12031.8036	6.2059	403.2354		
	Y2	-12031.7791	-12031.7774	6.2227	406.5086	The structural formula of	
	Y3	-12031.7785	-12031.7773	6.2196	405.8953		
						quaternary HA is XX'YZ, where	
FeZrTiSn	Y1	-23809.9415	-23809.9246	6.5143	466.3802		
	Y2	-23809.8856	-23809.8822	6.5632	476.9620	X X' and V belongs to transition	
	Y3	-23809.8857	-23809.8818	6.5645	477.2349	A, A and I belongs to transition	
						alamanta and 7 is the main success	
FeZrTiPb	Y1	-53308.9127	-53308.8932	6.5983	484.6630	elements and Z is the main group	
	Y2	-53308.8561	-53308.8527	6.6597	498.3081		
	Y3	-53308.8540	-53308.8518	6.6665	499.8387	(sp-group) element and it belongs	
						1	

- \blacktriangleright These alloys also satisfy the Slater-Pauling rule with magnetic moment of $M_T = 1$ N_v - 18 for half metallicity and as a result they have a total magnetic moment of 2µB.
- \blacktriangleright The highest Seebeck coecient value for FeZrTiZ (Z = Si, Sn, Pb) is 110.5 μ V/K, 121.8 µV/K and 100.6 µV/K respectively at the temperature 900K, 600K and 750K and the corresponding gure of merit is 0.85, 0.9 and 0.59.
- The observation of half metallicity indicate that these materials can be used in spintronic devices and the observation of substantial thermoelectric gure of merit suggest that these materials can be used in waste heat recovery.



Introduction

- Heusler alloys are not novel, they have been known for more than a century. They are named after the German chemist Friedrich Heusler, who in 1903 discovered that the full Heusler alloy Cu₂MnAl alloy exhibits a strong ferromagnetic behaviour.
- Half metalicity in Heusler alloy NiMnSb first discovered by Groot *et al.* in 1983

Spintronic

Spintronics is based on the spin of electrons rather



Charge 🖡

Technology.

- \blacktriangleright In order to investigate the thermoelectric properties of Heusler material, Boltzmann theory as applied in Boltz-Trap code is used and it is depend on the data provided by WIEN2k code.
- The lattice dynamical calculations were done using finite difference method to calculate the phonon spectrum using the Vienna of Ab initio simulation package (VASP) with PAW potential along with the Phonopy code



FeZrTiZ in Y1-type The optimized crystal structure of **Fig. 1.** (Leftmost), Y2 -type (middle) and Y3-type (rightmost) structure.

2. Mechanical stability

Parameter		FeZrTiSi	FeZrTiSn	FeZrTiPb
Elastic constants (in GPa)	C ₁₁ C ₁₂ C ₄₄	197.3 132.21 80.57	166.92 108.83 83.71	127.51 113.98 58.3
Youngs modulus (Y in Gpa)		208.93	181.71	153.92
Bulk modulus (B in Gpa)		153.90	128.19	118.49
Shear modulus (G in Gpa)		82.02	71.89	59.96
Pugh's ratio (B/G)		1.88	1.78	1.98
Poisson's ratio (υ)		0.27	0.26	0.28

- to F-43m space group.. Table 1. The equilibrium energy and lattice constant of FeZrTiZ
- \blacktriangleright The equilibrium structural parameters are obtained by fitting the total energy vs. volume curve with the help of Murnaghan equation of states
- \blacktriangleright Y-1 type structure is X = (0, 0, 0), X' = (0.25, 0.25, 0.25), Y = (0.5, 0.5, 0.5), Z = (0.75, 075, 0.75).

 \blacktriangleright Y-2 - X = (0, 0, 0), X' = (0.5, 0.5, 0.5), Y = (0.25, 0.25, 0.25), Z = (0.75, 075, 0.75) and



The thermodynamic stability of the materials is determined by the negative formation energy and further be confirmed by phonon dispersion curves where the material should possess all phonon modes with positive frequency in order to be dynamically stable.

> The number of atoms in the unit cell decides the number of optical modes. The 'n' number of atoms in the unit cell will exhibit 3n-n degree of optical mode of vibrations.



- than its charge
- The electrons can rotate either clockwise or anti around its own axis with constant clockwise frequency
- The two possible spin states represented as '0' and '1' in logical operations to store the data.





Factors affecting ZT



Strategies to improve ZT



	Anisotropy factor (A)	2.48	2.88	8.62
Spin	Hardness H _v	9.61	9.40	9.18
	Debye temperature θ _D (K)	491.6	397.1	323.2

4. Electronic property







W0 1 2 3 4 5 6 7 W X W01234567 X PDOS (States/THz) Wave vector Wave vector PDOS (States/THz) Wave vector

Fig. 3. The phonon dispersion frequency band and its corresponding PDOS of FeZrTiZ

5. Thermoelectric property







Where, S-Seebeck coefficient, σ electrical conductivity, temperature, κ_{e} - electron based thermal conductivity κ_L -lattice thermal conductivity

Phonon engineering – to have low κ by phonon scattering



Carrier Engineering- for enhancing Power factor

 Table 3. The calculated band gap and magnetic moment of FeZrTiZ

From the structural phase stability study we found that these compounds exhibit ferromagnetic behavior in their ground state and the calculated equilibrium volume and lattice parameters are listed. From the total energy calculations, we have found that all these three compounds are having negative formation energy and hence they can synthesize experimentally as stable compounds.

> The calculated elastic constants convey the mechanical stability of these alloys and they exhibit strong mechanical anisotropy with ductile behavior. The phonon dispersion curves obtained using finite difference method with the quasi harmonic approximation show all phonon frequencies possessing positive values suggesting they are dynamically stable.

From the analysis of calculated electronic structure, we found that these materials are having half metallic behavior with band gap value of 1.15eV, 1.1eV, 1.0eV for FeZrTiSi, FeZrTiSn and FeZrTiPb, respectively in their minority spin channel. The observation of HM behavior suggest that these materials can be used in spintronic applications.

The maximum obtained PF values are 10.93 × 10¹¹ W/m.K².s at 900K in FeZrCrSi, 10.10 × 10¹¹ W/m.K².s at 600K in FeZrTiSn and 9.04 × 10¹¹ W/m.K².s at 750K. From the calculated transport properties, we conclude that these materials possess reasonably high figure of merit at high temperature and hence they can be use in high temperature waste heat recovery process.

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